

FMMT620TA Datasheet



<https://www.DiGi-Electronics.com>

| | |
|------------------------------|--|
| DiGi Electronics Part Number | FMMT620TA-DG |
| Manufacturer | Diodes Incorporated |
| Manufacturer Product Number | FMMT620TA |
| Description | TRANS NPN 80V 1.5A SOT23-3 |
| Detailed Description | Bipolar (BJT) Transistor NPN 80 V 1.5 A 160MHz 625 mW Surface Mount SOT-23-3 |



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Purchase and inquiry

Manufacturer Product Number:

FMMT620TA

Series:

-

Transistor Type:

NPN

Voltage - Collector Emitter Breakdown (Max):

80 V

Current - Collector Cutoff (Max):

100nA

Power - Max:

625 mW

Operating Temperature:

-55°C ~ 150°C (TJ)

Package / Case:

TO-236-3, SC-59, SOT-23-3

Base Product Number:

FMMT620

Manufacturer:

Diodes Incorporated

Product Status:

Active

Current - Collector (Ic) (Max):

1.5 A

Vce Saturation (Max) @ Ib, Ic:

200mV @ 50mA, 1.5A

DC Current Gain (hFE) (Min) @ Ic, Vce:

300 @ 200mA, 2V

Frequency - Transition:

160MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SOT-23-3

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.21.0075

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

80V NPN SILICON LOW SATURATION TRANSISTOR IN SOT23

Features

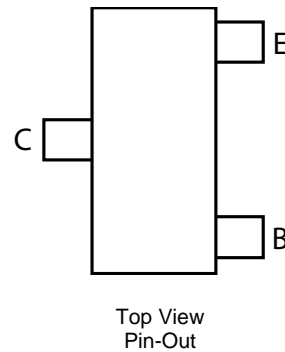
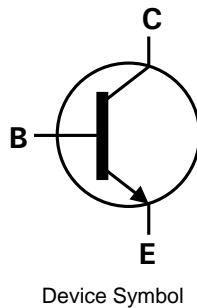
- $BV_{CEO} > 80V$
- $I_C = 1.5A$ Continuous Collector Current
- $R_{CE(SAT)} = 90m\Omega$ for a low equivalent On-Resistance
- 625mW Power dissipation
- h_{FE} specified up to 5A for high current gain hold up
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP capable (Note 4)**

Mechanical Data

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (E3)
- Weight 0.008 grams (approximate)

Applications

- DC-DC Modules
- Power Management Functions
- Motor control and drive functions
- CCFL Backlighting Inverters

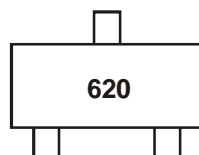


Ordering Information (Notes 4 & 5)

| Product | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|------------|------------|---------|--------------------|-----------------|-------------------|
| FMMT620TA | AEC-Q101 | 620 | 7 | 8 | 3,000 |
| FMMT620QTA | Automotive | 620 | 7 | 8 | 3,000 |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
 5. For packaging details, go to our website at <http://www.diodes.com>

Marking Information



620 = Product Type Marking Code

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

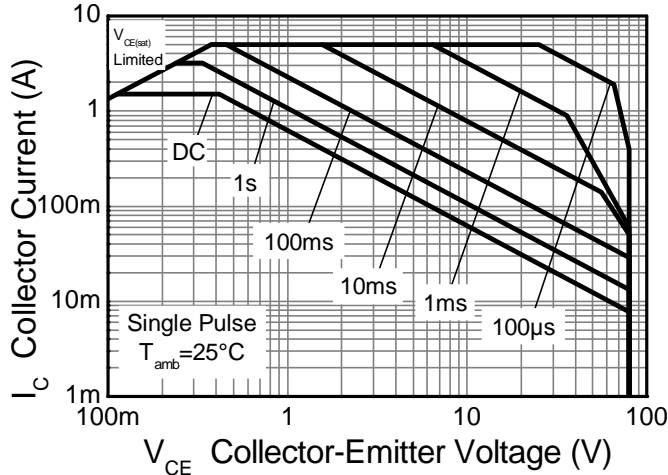
| Characteristic | Symbol | Value | Unit |
|------------------------------|-----------|-------|------|
| Collector-Base Voltage | V_{CBO} | 100 | V |
| Collector-Emitter Voltage | V_{CEO} | 80 | V |
| Emitter-Base Voltage | V_{EBO} | 7 | V |
| Continuous Collector Current | I_C | 1.5 | A |
| Peak Pulse Current | I_{CM} | 5 | A |
| Base Current | I_B | 500 | mA |

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

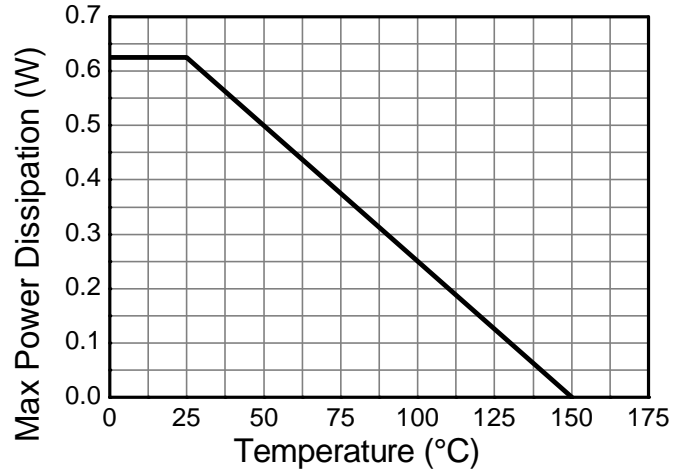
| Characteristic | Symbol | Value | Unit |
|--|-----------------|-------------|---------------------------|
| Power Dissipation (Note 6) | P_D | 625 | mW |
| Power Dissipation (Note 7) | P_D | 806 | mW |
| Thermal Resistance, Junction to Ambient (Note 6) | $R_{\theta JA}$ | 200 | $^\circ\text{C}/\text{W}$ |
| Thermal Resistance, Junction to Ambient (Note 7) | $R_{\theta JA}$ | 155 | $^\circ\text{C}/\text{W}$ |
| Thermal Resistance, Junction to Leads (Note 8) | $R_{\theta JL}$ | 194 | $^\circ\text{C}/\text{W}$ |
| Operating and Storage Temperature Range | T_J, T_{STG} | -55 to +150 | $^\circ\text{C}$ |

- Notes:
6. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 7. Same as note 6, except the device is measured at $t \leq 5$ sec.
 8. Thermal resistance from junction to solder-point (at the end of the collector lead).

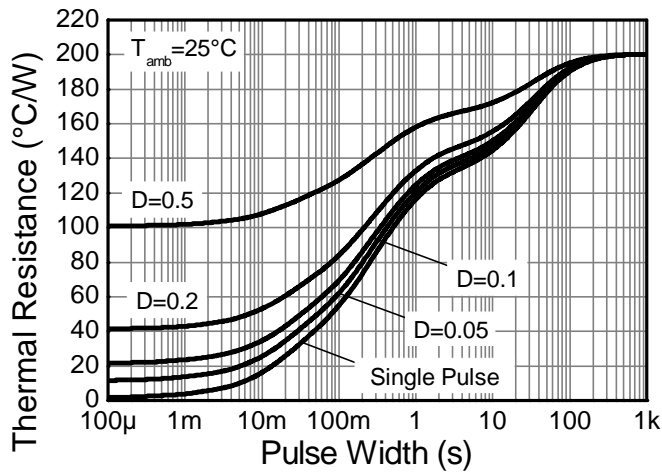
Thermal Characteristics and Derating information



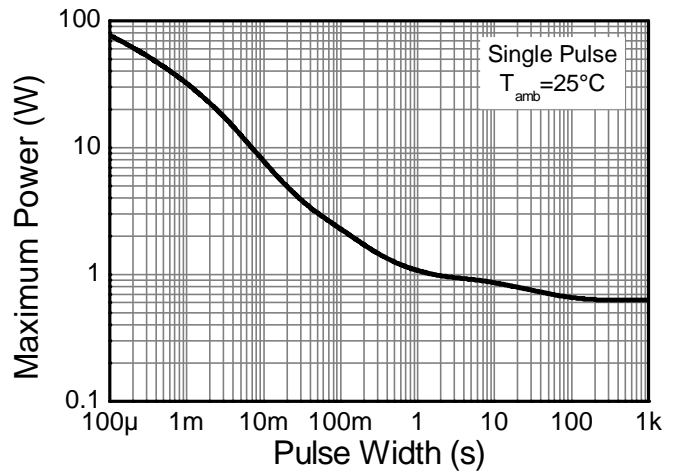
Safe Operating Area



Derating Curve



Transient Thermal Impedance



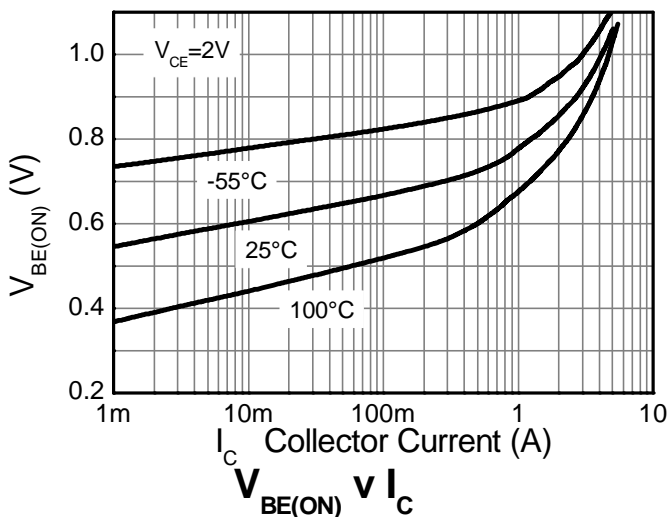
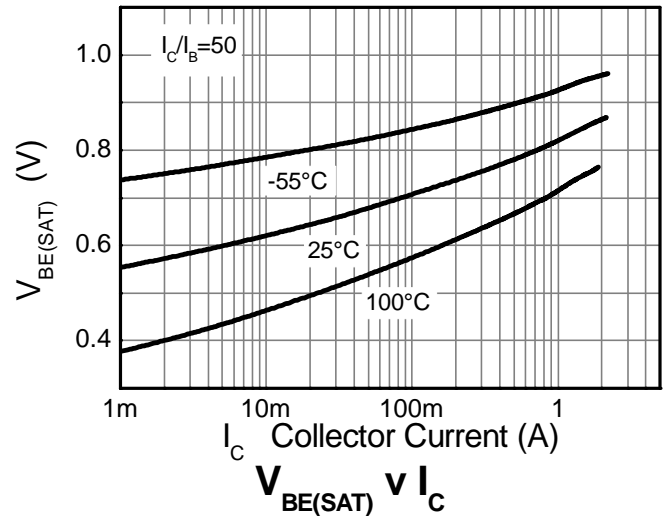
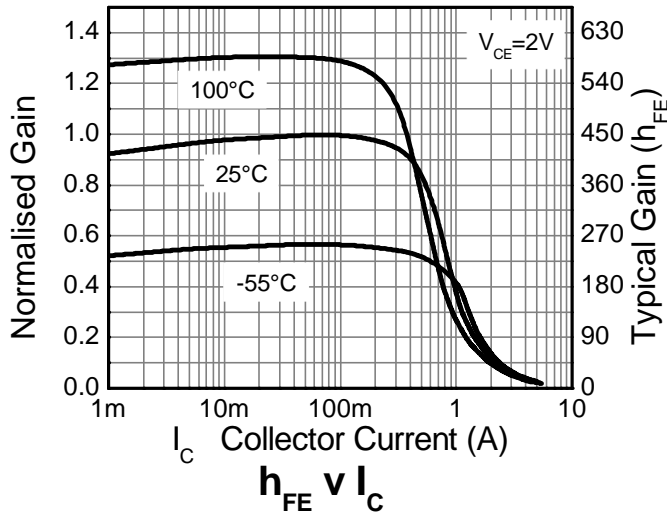
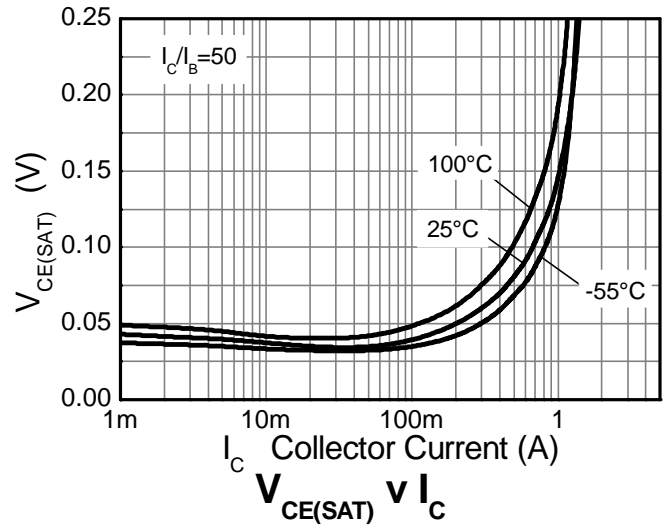
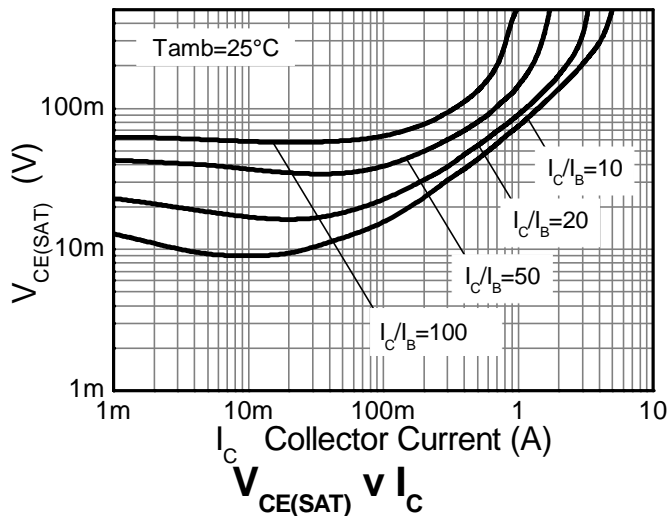
Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|--|----------------------|------------------------------------|-------------------------------------|------------------------------|------|---|
| Collector-Base Breakdown Voltage | BV _{CBO} | 100 | 180 | - | V | I _C = 100μA |
| Collector-Emitter Breakdown Voltage (Note 9) | BV _{CEO} | 80 | 110 | - | V | I _C = 1mA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | 7 | 8 | - | V | I _E = 100μA |
| Collector Cut-off Current | I _{CBO} | - | - | 100 | nA | V _{CB} = 80V |
| Emitter Cut-off Current | I _{EBO} | - | - | 100 | nA | V _{EB} = 6.0V |
| Collector Emitter Cut-off Current | I _{CES} | - | - | 100 | nA | V _{CES} = 80V |
| Static Forward Current Transfer Ratio (Note 9) | h _{FE} | 200 300 110 60 20 - | 450 450 170 90 30 10 | - 900 - - - - | - | I _C = 10mA, V _{CE} = 2V I _C = 200mA, V _{CE} = 2V I _C = 1A, V _{CE} = 2V I _C = 1.5A, V _{CE} = 2V I _C = 3A, V _{CE} = 2V I _C = 5A, V _{CE} = 2V |
| Collector-Emitter Saturation Voltage (Note 9) | V _{CE(sat)} | - - - - | 15 45 145 160 | 20 60 185 200 | mV | I _C = 0.1A, I _B = 10mA I _C = 0.5A, I _B = 50mA I _C = 1A, I _B = 20mA I _C = 1.5A, I _B = 20mA |
| Base-Emitter Saturation Voltage (Note 9) | V _{BE(sat)} | - | 0.86 | 1.0 | V | I _C = 1.5A, I _B = 50mA |
| Base-Emitter Saturation Voltage (Note 9) | V _{BE(on)} | - | 0.82 | 0.95 | V | I _C = 1.5A, V _{CE} = 2V |
| Transition Frequency | f _T | 100 | 160 | - | MHz | I _C = 50mA, V _{CE} = 10V, f = 100MHz |
| Collector Output Capacitance | C _{obo} | - | 11.5 | 18 | pF | V _{CB} = 10V, f = 1MHz |
| Turn-On Time | t _(on) | - | 86 | - | ns | V _{CC} = 10V, I _C = 500mA, |
| Turn-Off Time | t _(off) | - | 1128 | - | ns | I _{B1} = -I _{B2} = 25mA |

Notes: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%

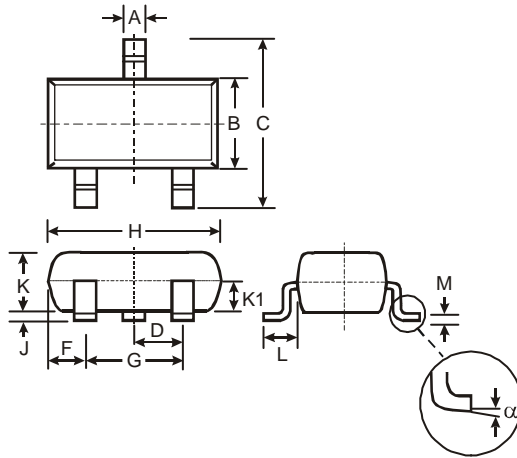
Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



FMMT620

Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

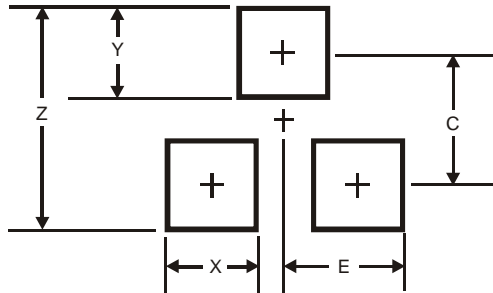


| SOT23 | | | |
|-------|-------|------|-------|
| Dim | Min | Max | Typ |
| A | 0.37 | 0.51 | 0.40 |
| B | 1.20 | 1.40 | 1.30 |
| C | 2.30 | 2.50 | 2.40 |
| D | 0.89 | 1.03 | 0.915 |
| F | 0.45 | 0.60 | 0.535 |
| G | 1.78 | 2.05 | 1.83 |
| H | 2.80 | 3.00 | 2.90 |
| J | 0.013 | 0.10 | 0.05 |
| K | 0.903 | 1.10 | 1.00 |
| K1 | - | - | 0.400 |
| L | 0.45 | 0.61 | 0.55 |
| M | 0.085 | 0.18 | 0.11 |
| α | 0° | 8° | - |

All Dimensions in mm

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.9 |
| X | 0.8 |
| Y | 0.9 |
| C | 2.0 |
| E | 1.35 |



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